

L Number	Hits	Search Text	DB	Time stamp
-	35	257/356 and trench and epitaxial	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/27 13:34
-	1	257/369 and trench and epitaxial and (oxide adj liner) and (dielectric adj layer) and wells	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/24 14:56
-	1	257/374 and trench and epitaxial and (oxide adj liner) and (dielectric adj layer) and wells	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/24 14:58
-	1	257/508 and trench and epitaxial and (oxide adj liner) and (dielectric adj layer) and wells	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/24 15:02
-	3	257/510 and trench and epitaxial and (oxide adj liner) and (dielectric adj layer) and wells	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/24 15:17
-	1	438/199 and trench and epitaxial and (oxide adj liner) and (dielectric adj layer) and wells	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/24 15:21
-	1	438/199 and trench and epitaxial and (oxide adj liner) and (dielectric adj layer) and wells and (annealing or heating or thermal\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/24 15:22
-	2	438/207 and trench and epitaxial and (oxide adj liner) and (dielectric adj layer) and wells and (annealing or heating or thermal\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/24 15:28
-	2	438/221 and trench and epitaxial and (oxide adj liner) and (dielectric adj layer) and wells and (annealing or heating or thermal\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/24 15:33
-	2	438/248 and trench and epitaxial and (oxide adj liner) and (dielectric adj layer) and wells and (annealing or heating or thermal\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/24 15:52
-	2	438/295 and trench and epitaxial and (oxide adj liner) and (dielectric adj layer) and wells and (annealing or heating or thermal\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/24 15:52
-	8	438/296 and trench and epitaxial and (oxide adj liner) and (dielectric adj layer) and wells and (annealing or heating or thermal\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/24 16:39
-	2	438/359 and trench and epitaxial and (oxide adj liner) and (dielectric adj layer) and wells and (annealing or heating or thermal\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/24 16:56
-	2	438/404 and trench and epitaxial and (oxide adj liner) and (dielectric adj layer) and wells and (annealing or heating or thermal\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/24 16:57

-	10	438/424 and trench and epitaxial and (oxide adj liner) and (dielectric adj layer) and wells and (annealing or heating or thermal\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/24 18:28
-	3	438/427 and trench and epitaxial and (oxide adj liner) and (dielectric adj layer) and wells and (annealing or heating or thermal\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/24 17:01
-	22	MOS and trench and epitaxial and (oxide adj liner) and (dielectric adj layer) and wells and (annealing or heating or thermal\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/25 08:26
-	105	438/424 and MOS and trench and (dielectric adj layer) and (annealing or heat or heating or thermal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/25 09:26
-	42	438/427 and MOS and trench and (dielectric adj layer) and (annealing or heat or heating or thermal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/25 09:37
-	93	438/296 and MOS and trench and (dielectric adj layer) and (annealing or heat or heating or thermal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/25 09:53
-	8	438/284 and MOS and trench and (dielectric adj layer) and (annealing or heat or heating or thermal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/25 09:54
-	75	438/199 and MOS and trench and (dielectric adj layer) and (annealing or heat or heating or thermal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/25 09:58
-	60	257/510 and MOS and trench and (dielectric adj layer) and (annealing or heat or heating or thermal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/02/25 09:59
-	1582	438/424	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/27 14:54
-	819	257/510	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/03 14:23
-	1	438/296 and (HPCVD)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/03 14:24
-	4	438/424 and (HPCVD)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/03 14:25
-	2	"20020055216"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/27 13:35

-	6	((pad adj layer) and (dielectric adj layer)) with (isotropically adj etch\$)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/27 15:00
-	4	438/\$.ccls. and (((pad adj layer) and (dielectric adj layer)) with (isotropically adj etch\$))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/27 15:01